

# isc N-Channel MOSFET Transistor

# IPW65R065C7

### • FEATURES

- Static drain-source on-resistance: R<sub>DS</sub>(on)≤65mΩ
- Enhancement mode:
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

## DESCRITION

· Fast Switching

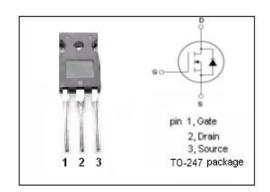


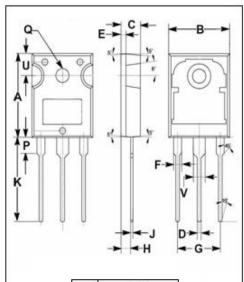
## • ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT	
$V_{ extsf{DSS}}$	Drain-Source Voltage	650	V	
V <sub>GS</sub>	Gate-Source Voltage	±20	V	
I <sub>D</sub>	Drain Current-Continuous	33	А	
I <sub>DM</sub>	Drain Current-Single Pulsed	145	А	
P <sub>D</sub>	Total Dissipation @T <sub>C</sub> =25℃	171	W	
Tj	Max. Operating Junction Temperature	150	$^{\circ}\!\mathbb{C}$	
T <sub>stg</sub>	Storage Temperature	-55~150	$^{\circ}$	

### • THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT	
Rth(j-c)	Channel-to-case thermal resistance	0.73	°C/W	
Rth(j-a)	Channel-to-ambient thermal resistance		°C/W	





	mm		
DIM	MIN	MAX	
Α	19.80	20.20	
В	15.40	15.80	
C	4.90	5.10	
D	0.90	1.10	
E	1.40	1.60	
F	1.90	2.10	
G	10.80	11.00	
Н	2.40	2.60	
J	0.50	0.70	
K	19.50	20.50	
P	3.90	4.10	
Q	3.30	3.50	
U	5.20	5.40	
V	2.90	3.10	



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#### **ELECTRICAL CHARACTERISTICS**

T<sub>C</sub>=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
BV <sub>DSS</sub>	Drain-Source Breakdown Voltage	V <sub>GS</sub> =0V; I <sub>D</sub> =1mA	650			V
V <sub>GS(th)</sub>	Gate Threshold Voltage	VDS=VGS; I <sub>D</sub> =0.85mA	3		4	V
R <sub>DS(on)</sub>	Drain-Source On-Resistance	V <sub>GS</sub> =10V; I <sub>D</sub> =17.1A			65	mΩ
I <sub>GSS</sub>	Gate-Source Leakage Current	V <sub>GS</sub> = 20V; V <sub>DS</sub> =0V			0.1	mA
I <sub>DSS</sub>	Drain-Source Leakage Current	V <sub>DS</sub> =650V; V <sub>GS</sub> = 0V			1	μ <b>А</b>
V <sub>SD</sub>	Diode forward voltage	I <sub>F</sub> =17.1A, V <sub>GS</sub> = 0V				V

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